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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet 1 of 2

Complete if Known	
Application Number	Not Yet Assigned
Filing Date	Herewith
First Named Inventor	Moeckley et al.
Group Art Unit	Not Yet Assigned
Examiner Name	Not Yet Assigned
Attorney Docket Number	844,004-303

Examiner Initials *	U.S. Patent Document Number	Kind Code[2] (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY
KMV	6,294,025		Kinder	05/14/1998
	6,527,866		Matijasevic et al.	03/04/2003
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KMV	2003/0146417		Romonovich et al.	08/07/2003

Examiner Initials*	Foreign Patent Document Office[3]	Number[4]	Kind Code[5] (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	T_6

Examiner Initials *	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume–issue number(s), publisher, city and/or country where published.	T^2
KMV	Brinkman, A. et al., "Superconducting Thin Films of MgB2 on Si by Pulsed Laser Deposition", Physica C 353 (2001), pp 1-4	
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Sheet 2 of 2

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Application Number	Not Yet Assigned
Filing Date	Herewith
First Named Inventor	Moeckley et al.
Group Art Unit	Not Yet Assigned
Examiner Name	Not Yet Assigned
Attorney Docket Number	844,004-303

Examiner Signature	/Kallambella Vijayakumar/	Date Considered	08/08/2006

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Sheet 1 of 1

Complete if Known	
Application Number	10/726,232
Filing Date	December 1, 2003
First Named Inventor	Brian Moeckly et al.
Group Art Unit	1765
Examiner Name	Not Yet Assigned
Attorney Docket Number	844004-303

Examiner Initials *	U.S. Patent Document Number	Kind Code[2] (*if known*)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY
KMV	US-4,420,385		Hartsough	12/13/1983

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Examiner Signature	/Kallambella Vijayakumar/	Date Considered	08/08/2006

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